



ELECTRICAL CHARACTERISTICS

	435	324	440	328	440	332	50	335	455	339
	40.3	37.6	40.5	37.8	40.3	38.0	30.9	38.2	41.1	38.4
	10.80	8.62	10.87	8.67	10.80	8.73	7.01	8.78	11.08	8.84
	49.0	45.6	49.2	45.8	49.0	46.0	39.6	46.2	49.8	46.4
	11.33	9.15	11.40	9.20	11.33	9.26	7.54	9.32	11.61	9.37
	20.00		20.20		20.40		20.70		20.90	

MECHANICAL CHARACTERISTICS

	Monocrystalline Silicon (9Busbar)
	144pcs in series (6*24)
	2094*1038*35mm (82.44*40.87*1.38inches)
	23.5kg (51.81lbs)
	3.2mm AR Coating Tempered Glass
	Anodized Aluminium Alloy
	IP68, 3 Bypass Diodes
	4mm ² (IEC), 12AWG(UL) 300mm in Length or Customized Length
	T01/LJQ-3-CSY/MC4/MC4-EV02

APPLICATION CONDITIONS

	1000V/1500V/DC
	-40°C~+85°C
	20A
	Class II

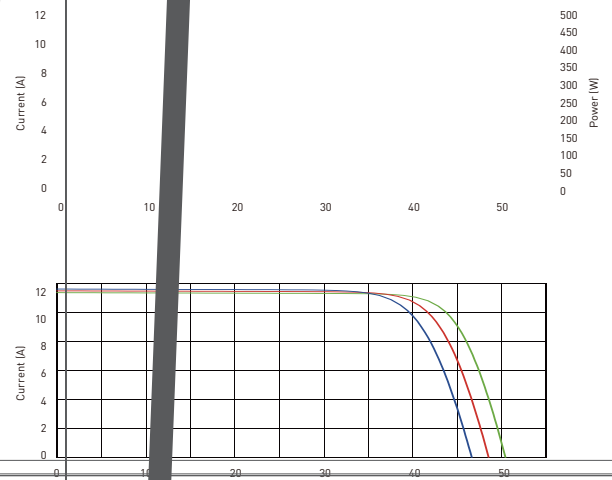
TEMPERATURE CHARACTERISTICS

	-0.36%/°C
	-0.26%/°C
	+0.043%/°C
	43±2°C

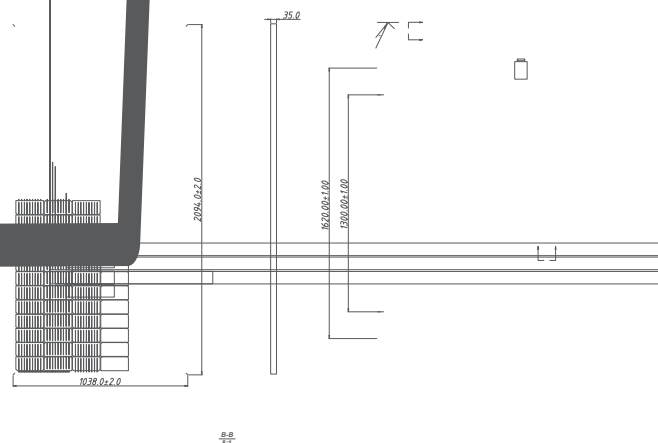
PACKING CONFIGURATION

	31	31(USA)
	715	682

I-V CURVE



TECHNICAL DRAWINGS



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